THE DATASHEET OF

MMDT3906-TP

Features

- Epitaxial Planar Die Construction
- Halogen Free. “Green” Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Dual PNP Small Signal Transistors

Maximum Ratings @ 25°C Unless Otherwise Specified

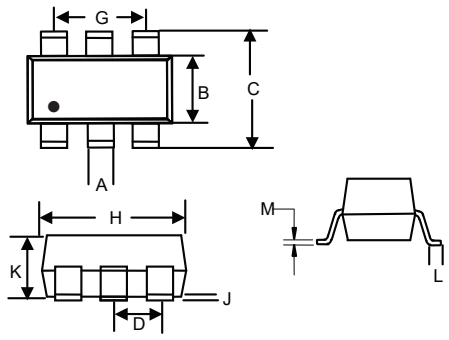
Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-200	mA
Collector Power Dissipation	P_C	200	mW

Thermal characteristics

Parameter	Symbol	Rating	Unit
Operating Junction Temperature Range	T_{OPR}	-55~+150	°C
Storage Temperature Range	T_{STR}	-55~+150	°C
Thermal Resistance from Junction to Ambient	$Rth_{(J-A)}$	625	°C/W

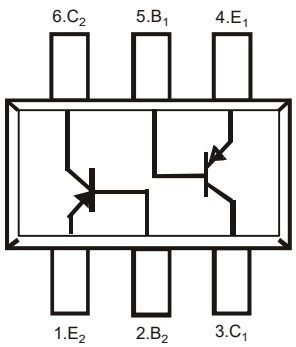
Note: 1. Halogen free "Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

SOT-363

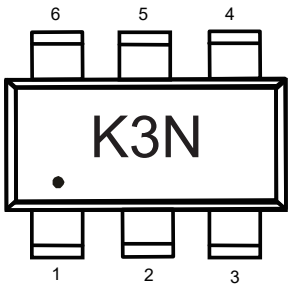


DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.006	0.014	0.15	0.35	
B	0.045	0.053	1.15	1.35	
C	0.079	0.096	2.00	2.45	
D	0.026		0.65		TYP.
G	0.047	0.055	1.20	1.40	
H	0.071	0.087	1.80	2.20	
J	-----	0.004	-----	0.10	
K	0.031	0.043	0.80	1.10	
L	0.010	0.018	0.26	0.46	
M	0.003	0.006	0.08	0.15	

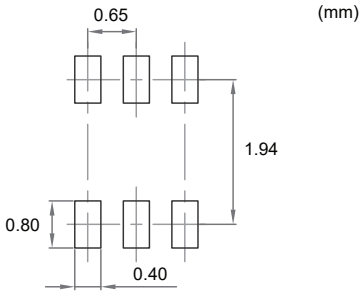
Internal Structure



Marking Code



Suggested Solder Pad Layout



Electrical Characteristics @ 25°C Unless Otherwise Specified

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40			V	I_C=-10μA, I_E=0
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-40			V	I_C=-1mA, I_B=0
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5			V	I_E=-10μA, I_C=0
Collector-Base Cutoff Current	I_{CBO}			-50	nA	V_{CB}=-30V, I_E=0
Emitter-Base Cutoff Current	I_{EBO}			-50	nA	V_{EB}=-5V, I_C=0
DC Current Gain	$h_{FE(1)}$	40				V_{CE}=-1V, I_C=-0.1mA
	$h_{FE(2)}$	70				V_{CE}=-1V, I_C=-1mA
	$h_{FE(3)}$	100		300		V_{CE}=-1V, I_C=-10mA
	$h_{FE(4)}$	60				V_{CE}=-1V, I_C=-50mA
	$h_{FE(5)}$	30				V_{CE}=-1V, I_C=-100mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			-0.25	V	I_C=-10mA, I_B=-1mA
				-0.4	V	I_C=-50mA, I_B=-5mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	-0.65		-0.85	V	I_C=-10mA, I_B=-1mA
				-0.95	V	I_C=-50mA, I_B=-5mA
Transition Frequency	f_T	250			MHz	V_{CE}=-20V, I_C=-10mA, f=100MHz
Output Capacitance	C_{ob}			4.5	pF	V_{CB}=-5V, I_E=0, f=1MHz
Noise Figure	NF			4	dB	V_{CE}=-5V, I_C=-0.1mA R_S=1KΩ, f=1KHz
Delay Time	t_d			35	ns	V_{CC}=-3V, I_C=-10mA
Rise Time	t_r			35	ns	V_{CE}=-0.5V, I_{B1}=-I_{B2}=-1mA
Storage Time	t_s			225	ns	V_{CC}=-3V, I_C=-10mA
Fall Time	t_f			75	ns	I_{B1}=I_{B2}=-1mA

Curve Characteristics

Fig. 1 - Static Characteristics

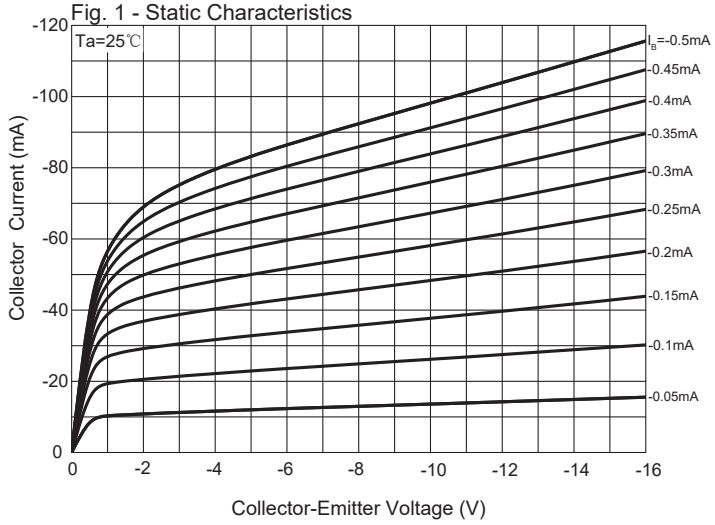


Fig. 2 - DC Current Gain Characteristics

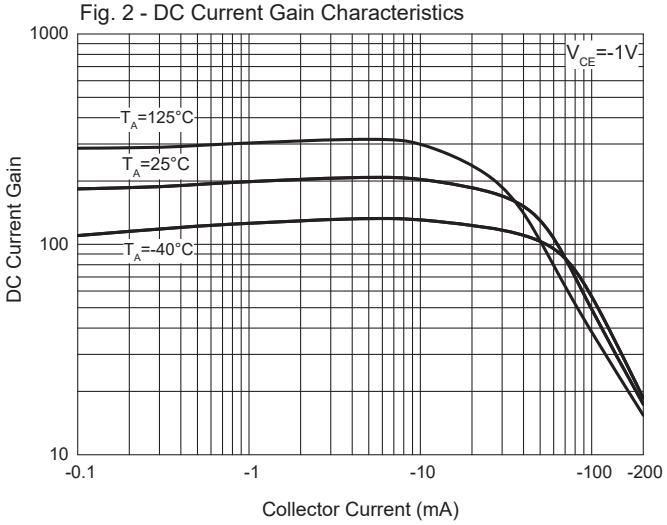


Fig. 3 - Collector-Emitter Saturation Voltage Characteristics

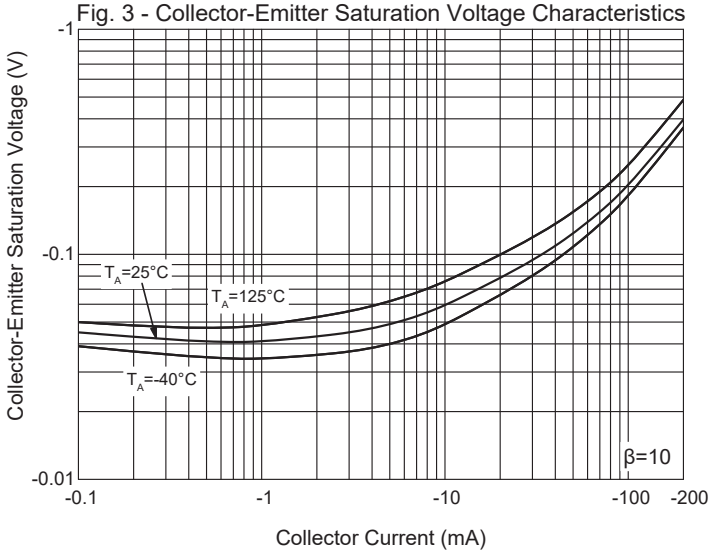


Fig. 4 - Base-Emitter Saturation Voltage Characteristics

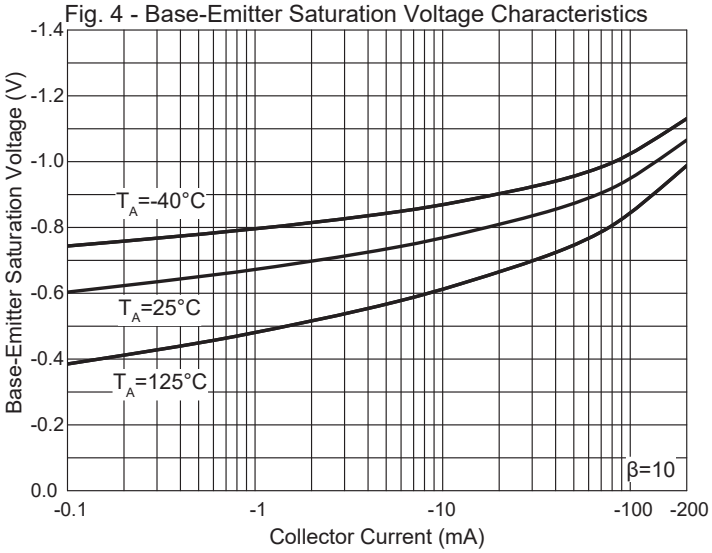


Fig. 5 - Base-Emitter Voltage Characteristics

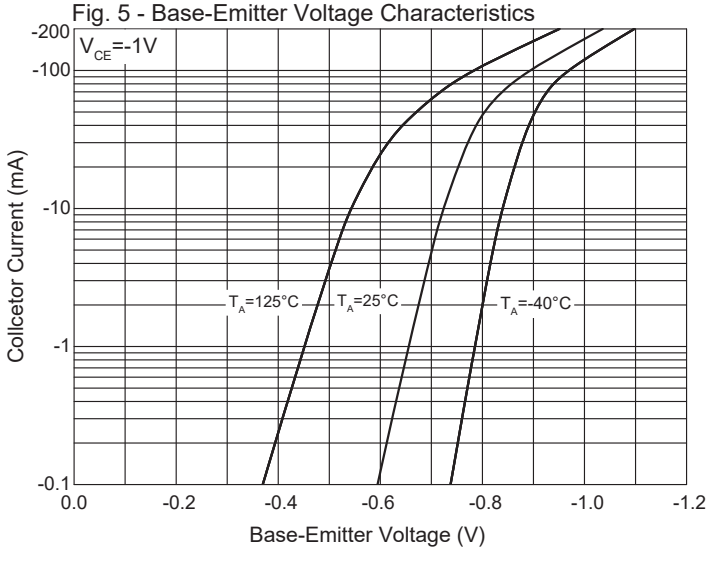
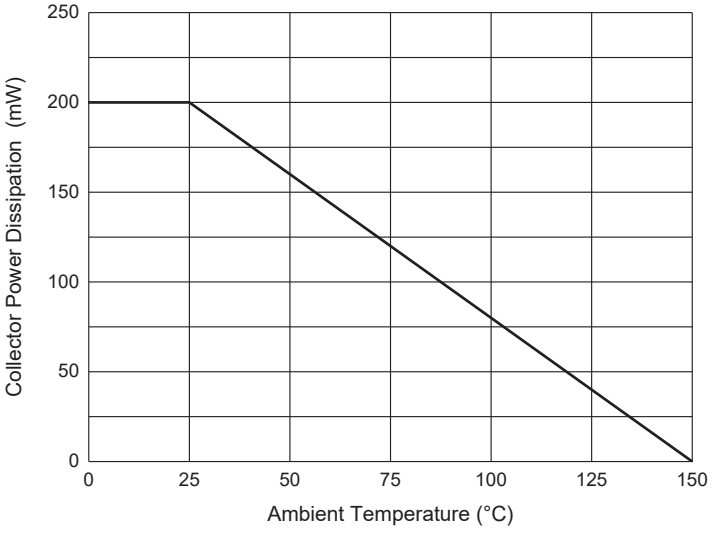


Fig. 6 - Collector Power Derating Curve



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel
Part Number-TPQ2	Tape&Reel: 3Kpcs/Reel

For packaging details,go to our website at https://www.mccsemi.com/pdf/ProductPackaging/SOT-363%20Package.pdf

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